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				Application Number	10/564,486-Conf. #9185	
11	IFORMATI	ON DISC	CLOSURE	Filing Date	January 13, 2006	
S	TATEMEN.	T BY AP	PLICANT	First Named Inventor	Hyo-Kun SON	
				Art Unit	2811	
	(Use as man)	y sheets as ned	cessary)	Examiner Name	J. Y. Miyoshi	
Sheet	1	of	1	Attorney Docket Number	3449-0567PUS1	

	U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number Number-Kind Code ^{2 (if known)}	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
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/J.M./	СА	KENJI UCHIDA, et al., "Photoluminescence Characteristics and Pit Formation of InGaN/GaN Quantum-Well Structures Grown on Sapphire Substrates by Low-Pressure Metalorganic Vapor Phase Epitaxy," Journal of Electronic Materials, Vol. 26, No. 3, 1999, pp. 246-251				

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